# 3.3 V 100/133 MHz **Differential 1:19 HCSL-Compatible Push-Pull Clock ZDB/Fanout Buffer for PCle<sup>®</sup>**



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#### Description

The NB3W1900L differential clock buffers are designed to work in conjunction with a PCIe compliant source clock synthesizer to provide point-to-point clocks to multiple agents. The device is capable of distributing the reference clocks for Intel<sup>®</sup> QuickPath Interconnect (Intel QPI), PCIe Gen1/Gen2/Gen3.The NB3W1900L internal PLL is optimized to support 100 MHz and 133 MHz frequency operation. The NB3W1900L is developed with the low-power NMOS Push-Pull buffer type.

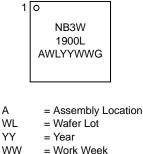
#### Features

- 19 Low Power Differential Clock Output Pairs @ 0.7 V
- Output-to-Output Skew Performance: < 85 ps
- Cycle-to-Cycle Jitter (PLL Mode): < 50ps
- Low Phase Jitter (Intel QPI, PCIe Gen 2/Gen 3 Phase Jitter Compliant)
- Input-to-Output Delay Variation: < 50 ps
- Fixed-Feedback for Lowest Input-to-Output Delay Variation
- Spread Spectrum Compatible; Tracks Input Clock Spreading for Low EMI
- 100 MHz and 133 MHz PLL Mode to Meet the Next Generation PCIe Gen2 / Gen 3 and Intel OPI Phase Jitter
- Individual OE Control via SMBus
- Low-Power NMOS Push-Pull HCSL-Compatible Outputs
- PLL Configurable for PLL Mode or Bypass Mode (Fanout Operation)
- SMBus Address Configurable to Allow Multiple Buffers in a Single Control Network
- Programmable PLL Bandwidth
- Two Tri-level Addresses Selection (Nine SMBus Addresses)
- QFN 72-pin Package, 10 mm × 10 mm
- These are Pb-Free Devices



QFN72 **MN SUFFIX** CASE 485DK

#### MARKING DIAGRAM



Α

G = Pb-Free Package

### ORDERING INFORMATION

See detailed ordering and shipping information on page 17 of this data sheet.

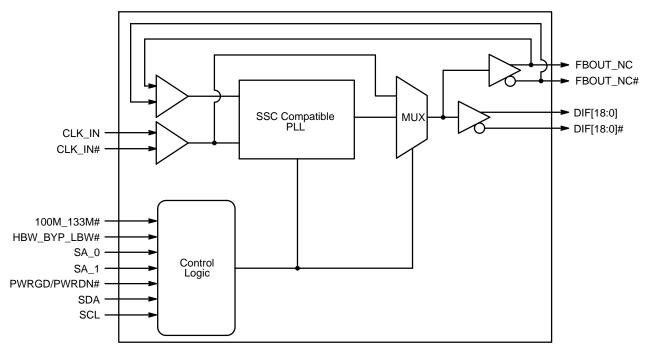
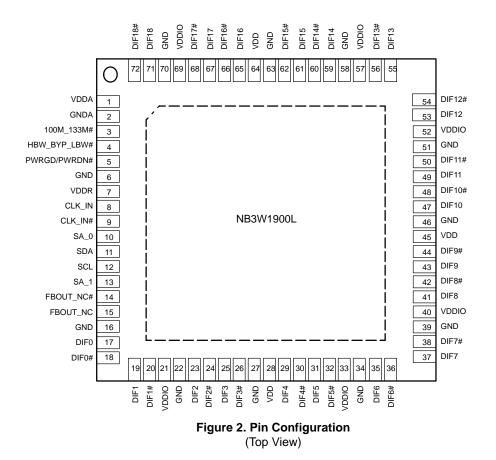


Figure 1. Simplified Block Diagram



### Table 1. POWER DOWN PIN TABLE

Inputs		Control Bits	C		
PWRGD/PWRDN#	CLK_IN / CLK_IN#	SMBus EN Bit	DIFx / DIFx#	FBOUT_NC / FBOUT_NC#	PLL Stage
0	Х	Х	Low/Low	Low/Low	OFF
1	Running	0	Low/Low	Running	ON
		1	Running	Running	ON

### Table 2. POWER CONNECTIONS

	Р	in Numbe	r	
VDD	VDDIO	VDDR	GND	Description
		7	2	Analog Input
1			6	Analog PLL
28, 45, 64	21, 33, 40, 52, 57, 69		16, 22, 27, 34, 39, 46, 51, 58, 63, 70	DIF clocks

### Table 3. TRI-LEVEL INPUT THRESHOLDS

Level	Voltage
Low	< 0.8 V
Mid	1.2 < Vin < 1.8 V
High	Vin > 2.2 V

### Table 4. FUNCTIONALITY AT POWER-UP (PLL Mode)

	CLK_IN	DIFx
100M_133M#	MHz	MHz
1	100.00	CLK_IN
0	133.33	CLK_IN

### Table 5. PLL OPERATING MODE

HBW_BYP_LBW#	MODE
Low	PLL Lo BW
Mid	Bypass
High	PLL Hi BW

NOTE: PLL is OFF in Bypass

### Table 6. MODE TRI-LEVEL INPUT THRESHOLD

Level	Voltage
Low	< 0.8 V
Mid	1.2 < Vin < 1.8 V
High	Vin > 2.2 V

### Table 7. NB3W1900L PIN DESCRIPTIONS

Pin Number	Pin Name	Туре	Description
1	VDDA	PWR	3.3 V Power Supply for PLL core.
2	GNDA	GND	Ground for PLL core.
3	100M_133M#	IN	Input to select operating frequency. See functionality table for definition.
4	HBW_BYP_LBW#	IN	Tri-level input to select High BW, Bypass or low BW mode. See PLL operating mode table for definition.
5	PWRGD/PWRDN#	IN	Notifies device to sample latched inputs and start up on first high assertion, or exit power down mode on subsequent assertions. Low enters power down mode.
6	GND	GND	Ground pin
7	VDDR	PWR	3.3 V power for differential input clock (receiver). This VDD should be treated as an analog power rail and filtered appropriately.
8	CLK_IN	IN	0.7 V differential true input
9	CLK_IN#	IN	0.7 V differential complementary input
10	SA_0	IN	SMBus address bit. This is a tri-level input that works in conjunction with the SA_1 to decode 1 of 9 SMBus addresses.
11	SDA	I/O	Data pin of SMBus circuitry, 5 V tolerant
12	SCL	IN	Clock pin of SMBus circuitry, 5 V tolerant
13	SA_1	IN	SMBus address bit. This is a tri-level input that works in conjunction with the SA_0 to decode 1 of 9 SMBus addresses.
14	FBOUT_NC#	OUT	Complementary half of differential feedback output. This pin should NOT be connected to anything outside the chip. It exists to provide delay path matching to get 0 ps propagation delay.
15	FBOUT_NC	OUT	True half of differential feedback output. This pin should NOT be connected to anything outside the chip. It exists to provide delay path matching to get 0 propagation delay.
16	GND	GND	Ground pin
17	DIF0	OUT	0.7 V differential true clock output
18	DIF0#	OUT	0.7 V differential complementary clock output
19	DIF1	OUT	0.7 V differential true clock output
20	DIF1#	OUT	0.7 V differential complementary clock output
21	VDDIO	PWR	Power supply for differential outputs
22	GND	GND	Ground pin
23	DIF2	OUT	0.7 V differential true clock output
24	DIF2#	OUT	0.7 V differential complementary clock output
25	DIF3	OUT	0.7 V differential true clock output
26	DIF3#	OUT	0.7 V differential complementary clock output
27	GND	GND	Ground pin
28	VDD	PWR	Power supply nominal 3.3 V
29	DIF4	OUT	0.7 V differential true clock output
30	DIF4#	OUT	0.7 V differential complementary clock output
31	DIF5	OUT	0.7 V differential true clock output
32	DIF5#	OUT	0.7 V differential complementary clock output
33	VDDIO	PWR	Power supply for differential outputs
34	GND	GND	Ground pin
35	DIF6	OUT	0.7 V differential true clock output

1. All VDD, VDDR, VDDIO, VDDA and GND pins must be externally connected to a power supply for proper operation.

### Table 7. NB3W1900L PIN DESCRIPTIONS (continued)

Pin Number	Pin Name	Туре	Description
36	DIF6#	OUT	0.7 V differential complementary clock output
37	DIF7	OUT	0.7 V differential true clock output
38	DIF7#	OUT	0.7 V differential complementary clock output
39	GND	GND	Ground pin
40	VDDIO	PWR	Power supply for differential outputs
41	DIF8	OUT	0.7 V differential true clock output
42	DIF8#	OUT	0.7 V differential complementary clock output
43	DIF9	OUT	0.7 V differential true clock output
44	DIF9#	OUT	0.7 V differential complementary clock output
45	VDD	PWR	Power supply nominal 3.3 V
46	GND	GND	Ground pin
47	DIF10	OUT	0.7 V differential true clock output
48	DIF10#	OUT	0.7 V differential complementary clock output
49	DIF11	OUT	0.7 V differential true clock output
50	DIF11#	OUT	0.7 V differential complementary clock output
51	GND	GND	Ground pin
52	VDDIO	PWR	Power supply for differential outputs
53	DIF12	OUT	0.7 V differential true clock output
54	DIF12#	OUT	0.7 V differential complementary clock output
55	DIF13	OUT	0.7 V differential true clock output
56	DIF13#	OUT	0.7 V differential complementary clock output
57	VDDIO	PWR	Power supply for differential outputs
58	GND	GND	Ground pin
59	DIF14	OUT	0.7 V differential true clock output
60	DIF14#	OUT	0.7 V differential complementary clock output
61	DIF15	OUT	0.7 V differential true clock output
62	DIF15#	OUT	0.7 V differential complementary clock output
63	GND	GND	Ground pin
64	VDD	PWR	Power supply nominal 3.3 V
65	DIF16	OUT	0.7 V differential true clock output
66	DIF16#	OUT	0.7 V differential complementary clock output
67	DIF17	OUT	0.7 V differential true clock output
68	DIF17#	OUT	0.7 V differential complementary clock output
69	VDDIO	PWR	Power supply for differential outputs
70	GND	GND	Ground pin
71	DIF18	OUT	0.7 V differential true clock output
72	DIF18#	OUT	0.7 V differential complementary clock output
EP	Exposed Pad	Thermal	The Exposed Pad (EP) on the QFN-72 package bottom is thermally connected to the die for improved heat transfer out of package. The exposed pad must be attached to a heat-sinking conduit. The pad is electrically connected to the die, and must be electrically and thermally connected to GND on the PC board.

1. All VDD, VDDR, VDDIO, VDDA and GND pins must be externally connected to a power supply for proper operation.

#### Table 8. ABSOLUTE MAXIMUM RATINGS (Note 2)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>DD</sub> / V <sub>DDA</sub> / V <sub>DDR</sub>	3.3 V Core Supply Voltage (Note 3)				4.6	V
V <sub>DD</sub> / V <sub>DDIO</sub>	3.3 V Logic and Output Supply Voltage (Note 3)				4.6	V
V <sub>IH</sub>	Input High Voltage	Except for SMBus Interface			V <sub>DD</sub> + 0.5	V
VIH	VIHSMB	SMBus Clock and Data Pins			5.5	V
V <sub>IL</sub>	Input Low Voltage		GND - 0.5		-	V
Ts	Storage Temperature		-65		150	°C
Τ <sub>J</sub>	Junction Temperature				125	°C
ESD prot.	ESD Protection (Human Body)	Human Body Model	2000			V
θJA	Thermal Resistance Junction-to-Ambient	Still air		18.1		°C/W
θJC	Thermal Resistance Junction-to-Case			5.0		°C/W

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

Guaranteed by design and characterization, not tested in production.

3. Operation under these conditions is neither implied nor guaranteed.

### Table 9. ELECTRICAL CHARACTERISTICS – CLOCK INPUT PARAMETERS

 $(T_A = 0^{\circ}C - 70^{\circ}C;$  Supply Voltage  $V_{DD}/V_{DDA} = 3.3 \text{ V} \pm 5\%$ ,  $V_{DDIO} = 1.05$  to  $3.3 \text{ V} \pm 5\%$ . See Test Loads for Loading Conditions) (Note 4)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>IHDIF</sub>	Input High Voltage – CLK_IN	Differential Inputs (single-ended measurement)	600		1150	mV
V <sub>ILDIF</sub>	Input Low Voltage – CLK_IN	Differential Inputs (single-ended measurement)	V <sub>SS</sub> – 300		300	mV
V <sub>COM</sub>	Input Common Mode Voltage – CLK_IN (not spec'd)	Common Mode Input Voltage	300		1000	mV
V <sub>SWING</sub>	Input Amplitude – CLK_IN not spec'd	Peak to Peak Value	300		1450	mV
dv/dt	Input Slew Rate – CLK_IN (Note 5)	Measured Differentially	0.4		8	V/ns
I <sub>IN</sub>	Input Leakage Current	$V_{IN} = V_{DD}, V_{IN} = GND$	-5		5	μΑ
d <sub>tin</sub>	Input Duty Cycle	Measurement from Differential Waveform	45		55	%
J <sub>DIFIn</sub>	Input Jitter – Cycle to Cycle	Differential Measurement	0		125	ps

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

4. Guaranteed by design and characterization, not tested in production.

5. Slew rate measured through ±75 mV window centered around differential zero

#### Table 10. ELECTRICAL CHARACTERISTICS-INPUT/SUPPLY/COMMON OUTPUT PARAMETERS

 $(T_A = 0^{\circ}C - 70^{\circ}C;$  Supply Voltage V<sub>DD</sub>/V<sub>DDA</sub> = 3.3 V ±5%, V<sub>DDIO</sub> = 1.05 V to 3.3 V ±5%. See Test Loads for Loading Conditions) (Note 6)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit	
V <sub>IH</sub>	Input High Voltage	Single-ended inputs, except SMBus, low threshold and tri-level inputs	2		V <sub>DD</sub> + 0.3	V	
V <sub>IL</sub>	Input Low Voltage	Single-ended inputs, except SMBus, low threshold and tri–level inputs	GND – 0.3		0.8	V	
I <sub>IN</sub>	Input Current	Single-ended inputs, $V_{IN} = GND$ , $V_{IN} = V_{DD}$	-5		5	μΑ	
$V_{IH_FS}$	Input High Voltage	(Note 7)	0.7		V <sub>DD</sub> + 0.3	V	
$V_{IL_FS}$	Input Low Voltage	(Note 7)	GND – 0.3		0.35	V	

### Table 10. ELECTRICAL CHARACTERISTICS-INPUT/SUPPLY/COMMON OUTPUT PARAMETERS (continued)

(T<sub>A</sub> = 0°C - 70°C; Supply Voltage V<sub>DD</sub>/V<sub>DDA</sub> = 3.3 V ±5%, V<sub>DDIO</sub> = 1.05 V to 3.3 V ±5%. See Test Loads for Loading Conditions) (Note 6)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
F <sub>ibyp</sub>	Input Frequency	V <sub>DD</sub> = 3.3 V, Bypass mode (Note 8)	33		150	MHz
F <sub>ipll</sub>		V <sub>DD</sub> = 3.3 V, 100.00 MHz PLL mode (Note 8)	99	100.00	101	MHz
F <sub>ipll</sub>		V <sub>DD</sub> = 3.3 V, 133.33 MHz PLL mode (Note 8)	132.33	133.33	134.33	MHz
L <sub>pin</sub>	Pin Inductance				7	nH
C <sub>IN</sub>	Capacitance	Logic Inputs, except CLK_IN	1.5		5	pF
CINCLK_IN		CLK_IN differential clock inputs (Note 10)	1.5		2.7	pF
C <sub>OUT</sub>		Output pin capacitance			6	pF
T <sub>STAB</sub>	Clk Stabilization (Note 8)	From V <sub>DD</sub> Power-Up and after input clock stabilization or de-assertion of PD# to 1st clock			1	ms
f <sub>MODIN</sub>	Input SS Modulation Frequency	Allowable Frequency (Triangular Modulation)	30		33	kHz
t <sub>LATOE</sub> #	OE# Latency	DIF start after OE# assertion DIF stop after OE# de-assertion	4		12	clocks
t <sub>DRVPD</sub>	Tdrive_PD# (Note 9)	DIF output enable after PD# de-assertion			300	μs
t <sub>F</sub>	Tfall (Note 8)	Fall time of control inputs			5	ns
t <sub>R</sub>	Trise (Note 8)	Rise time of control inputs			5	ns
V <sub>ILSMB</sub>	SMBus Input Low Voltage				0.8	V
V <sub>IHSMB</sub>	SMBus Input High Voltage		2.1		V <sub>DDSMB</sub>	V
V <sub>OLSMB</sub>	SMBus Output Low Voltage	@ IPULLUP			0.4	V
I <sub>PULLUP</sub>	SMBus Sink Current	@ V <sub>OL</sub>	4			mA
V <sub>DDSMB</sub>	Nominal Bus Voltage	3 V to 5 V ±10%	2.7		5.5	V
t <sub>RSMB</sub>	SCL/SDA Rise Time	(Max VIL – 0.15) to (Min VIH + 0.15)			1000	ns
t <sub>FSMB</sub>	SCL/SDA Fall Time	(Min VIH + 0.15) to (Max VIL - 0.15)			300	ns
f <sub>MAXSMB</sub>	SMBus Operating Frequency (Note 11)	Maximum SMBus operating frequency			100	kHz

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 6. Guaranteed by design and characterization, not tested in production.

100M\_133M# Frequency Select (FS).
 Control input must be monotonic from 20% to 80% of input swing.

9. Time from de-assertion until outputs are > 200 mV

10.CLK\_IN input

11. The differential input clock must be running for the SMBus to be active

#### Table 11. ELECTRICAL CHARACTERISTICS – DIF 0.7 V LOW POWER DIFFERENTIAL OUTPUTS

(T<sub>A</sub> = 0°C – 70°C; Supply Voltage V<sub>DD</sub>/V<sub>DDA</sub> = 3.3 V  $\pm$ 5%, V<sub>DDIO</sub> = 1.05 V to 3.3 V  $\pm$ 5%. See Test Loads for Loading Conditions) (Note 12)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
dV/dt	Slew Rate (Notes 13, 14)	Scope averaging on	1		4	V/ns
$\Delta dV/dt$	Slew Rate Matching (Notes 13, 15)	Slew rate matching, Scope averaging on			20	%
V <sub>High</sub>	Voltage High	Statistical measurement on single-ended	660		850	mV
V <sub>Low</sub>	Voltage Low	signal using oscilloscope math function. (Scope averaging on)	-150		150	
V <sub>max</sub>	Max Voltage	Measurement on single ended signal using			1150	mV
V <sub>min</sub>	Min Voltage	Absolute value. (Scope averaging off)	-300			
V <sub>swing</sub>	Vswing (Note 13)	Scope averaging off	300			mV
V <sub>cross_abs</sub>	Crossing Voltage (abs) (Note 16)	Scope averaging off	250		550	mV
$\Delta V_{cross}$	Crossing Voltage (var) (Note 17)	Scope averaging off			140	mV

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

12. Guaranteed by design and characterization, not tested in production.  $C_L = 2 \text{ pF}$  with  $R_S = 33 \Omega$  for Zo = 50  $\Omega$  (100  $\Omega$  differential trace impedance).

13. Measured from differential waveform

14. Slew rate is measured through the V<sub>swing</sub> voltage range centered around differential 0 V. This results in a ±150 mV window around differential 0 V.

15. Matching applies to rising edge rate for Clock and falling edge rate for Clock#. It is measured using a ±75 mV window centered on the average cross point where Clock rising meets Clock# falling. The median cross point is used to calculate the voltage thresholds the oscilloscope is to use for the edge rate calculations.

16. V<sub>cross</sub> is defined as voltage where Clock = Clock# measured on a component test board and only applies to the differential rising edge (i.e. Clock rising and Clock# falling).

17. The total variation of all  $V_{cross}$  measurements in any particular system. Note that this is a subset of  $V_{cross\_min/max}$  ( $V_{cross}$  absolute) allowed. The intent is to limit  $V_{cross}$  induced modulation by setting  $\Delta V_{cross}$  to be smaller than  $V_{cross}$  absolute.

### Table 12. ELECTRICAL CHARACTERISTICS – CURRENT CONSUMPTION

 $(T_A = 0^{\circ}C - 70^{\circ}C;$  Supply Voltage  $V_{DD}/V_{DDA} = 3.3 \text{ V} \pm 5\%$ ,  $V_{DDIO} = 1.05 \text{ V}$  to 3.3 V  $\pm 5\%$ . See Test Loads for Loading Conditions) (Note 18)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I <sub>DDVDD</sub>	Operating Supply Current	All outputs @ 100.00 MHz, CL = 2 pF; Zo = 85 $\Omega$			50	mA
I <sub>DDVDDA/R</sub>		All outputs @ 100.00 MHz, C <sub>L</sub> = 2 pF; Zo = 85 $\Omega$			30	mA
I <sub>DDVDDIO</sub>		All outputs @ 100.00 MHz, C <sub>L</sub> = 2 pF; Zo = 85 $\Omega$			200	mA
IDDVDDPD	Powerdown Current (Note 19)	All differential pairs low/low			4	mA
I <sub>DDVDDA/RPD</sub>		All differential pairs low/low			5	mA
IDDVDDIOPD		All differential pairs low/low			0.2	mA

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

18. Guaranteed by design and characterization, not tested in production.

19. With input clock running. Stopping the input clock will result in lower numbers.

### Table 13. ELECTRICAL CHARACTERISTICS – SKEW AND DIFFERENTIAL JITTER PARAMETERS

 $(T_A = 0^{\circ}C - 70^{\circ}C;$  Supply Voltage  $V_{DD}/V_{DDA} = 3.3 \text{ V} \pm 5\%$ ,  $V_{DDIO} = 1.05$  to  $3.3 \text{ V} \pm 5\%$ . See Test Loads for Loading Conditions)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
tSPO_PLL	CLK_IN, DIF[x:0] (Notes 20, 21, 23, 24 and 27)	Input-to-Output Skew in PLL mode nominal value @ 25°C, 3.3 V	-100		100	ps
t <sub>PD_BYP</sub>	CLK_IN, DIF[x:0] (Notes 20, 21, 22, 24 and 27)	Input-to-Output Skew in Bypass mode nominal value @ 25°C, 3.3 V	2.5		4.5	ns
tDSPO_PLL	CLK_IN, DIF[x:0] (Notes 20, 21, 22, 24 and 27)	Input-to-Output Skew Variation in PLL mode across voltage and temperature			100	ps
t <sub>DSPO_BYP</sub>	CLK_IN, DIF[x:0] (Notes 20, 21, 22, 24 and 27)	Input-to-Output Skew Variation in Bypass mode across voltage and temperature	-250		250	ps
t <sub>DTE</sub>	CLK_IN, DIF[x:0] (Notes 20, 21, 22, 24 and 27)	Random Differential Tracking error between two NB3W1900L devices in Hi BW Mode			5	ps (rms)
t <sub>DSSTE</sub>	CLK_IN, DIF[x:0] (Notes 20, 21, 22, 24 and 27)	Random Differential Spread Spectrum Tracking error between two NB3W1900L devices in Hi BW Mode.			75	ps
t <sub>SKEW_ALL</sub>	DIF[x:0] (Notes 20, 21, 22 and 27)	Output-to-Output Skew across all outputs (Common to Bypass and PLL mode)			85	ps
jpeak-hibw	PLL Jitter Peaking (Notes 26 and 27)	HBW_BYP_LBW# = 1	0		2.5	dB
j <sub>peak-lobw</sub>	PLL Jitter Peaking (Notes 26 and 27)	HBW_BYP_LBW# = 0	0		2	dB
pll <sub>HIBW</sub>	PLL Bandwidth (Notes 27 and 28)	HBW_BYP_LBW# = 1	2		4	MHz
pll <sub>LOBW</sub>	PLL Bandwidth (Notes 27 and 28)	HBW_BYP_LBW# = 0	0.7		1.4	MHz
t <sub>DC</sub>	Duty Cycle (Note 20)	Measured differentially, PLL Mode	45	50	55	%
t <sub>DCD</sub>	Duty Cycle Distortion (Notes 20 and 29)	Measured differentially, Bypass Mode @ 100.00 MHz	-2	0	2	%
t <sub>jcyc-cyc</sub>	Jitter, Cycle-to-Cycle	PLL mode			50	ps
	(Notes 20 and 30)	Additive Jitter in Bypass Mode			50	ps

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

20. Measured into fixed 2 pF load cap. Input to output skew is measured at the first output edge following the corresponding input.

21. Measured from differential cross-point to differential cross-point. This parameter can be tuned with external feedback path, if present.

22. All Bypass Mode Input-to-Output specs refer to the timing between an input edge and the specific output edge created by it.

23. This parameter is deterministic for a given device

24. Measured with scope averaging on to find mean value.

25.t is the period of the input clock

26. Measured as maximum pass band gain. At frequencies within the loop BW, highest point of magnification is called PLL jitter peaking. 27. Guaranteed by design and characterization, not tested in production.

28. Measured at 3 db down or half power point.

29. Duty cycle distortion is the difference in duty cycle between the output and the input clock when the device is operated in bypass mode. 30. Measured from differential waveform

### Table 14. ELECTRICAL CHARACTERISTICS – PHASE JITTER PARAMETERS

 $(T_A = 0^{\circ}C - 70^{\circ}C; Supply Voltage V_{DD}/V_{DDA} = 3.3 V \pm 5\%, V_{DDIO} = 1.05 V to 3.3 V \pm 5\%$ . See Test Loads for Loading Conditions) (Note 31)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
t <sub>jphPCleG1</sub>	Phase Jitter, PLL Mode	PCIe Gen 1 (Notes 32 and 33)			86	ps (p–p)
t <sub>jphPCleG2</sub>		PCIe Gen 2 Lo Band 10 kHz < f < 1.5 MHz (Note 32)			3	ps (rms)
		PCIe Gen 2 High Band 1.5 MHz < f < Nyquist (50 MHz) (Note 32)			3.1	ps (rms)
<sup>t</sup> jphPCleG3		PCIe Gen 3 (PLL BW of 2–4 MHz, CDR = 10 MHz) (Notes 32, 33 and 34)			1	ps (rms)
<sup>t</sup> jphQPI_SMI		QPI & SMI (100.00 MHz or 133.33 MHz, 4.8 Gb/s, 6.4 Gb/s 12UI) (Note 35)			0.5	ps (rms)
		QPI & SMI (100.00 MHz, 8.0 Gb/s, 12UI) (Note 35)			0.3	ps (rms)
		QPI & SMI (100.00 MHz, 9.6 Gb/s, 12UI) (Note 35)			0.2	ps (rms)
t <sub>jphPCleG1</sub>	Additive Phase Jitter, Bypass Mode	PCIe Gen 1 (Notes 32 and 33)			10	ps (p–p)
t <sub>jphPCleG2</sub>		PCIe Gen 2 Lo Band 10 kHz < f < 1.5 MHz (Notes 32 and 36)			0.3	ps (rms)
		PCIe Gen 2 High Band 1.5 MHz < f < Nyquist (50 MHz) (Notes 32 and 36)			0.7	ps (rms)
t <sub>jph</sub> PCleG3		PCIe Gen 3 (PLL BW of 2–4 MHz, CDR = 10 MHz) (Notes 32, 34 and 36)			0.3	ps (rms)
t <sub>jphQPI_SMI</sub>		QPI & SMI (100.00 MHz or 133.33 MHz, 4.8 Gb/s, 6.4 Gb/s 12UI) (Notes 35 and 36)			0.3	ps (rms)
		QPI & SMI (100.00 MHz, 8.0 Gb/s, 12UI) (Notes 35 and 36)			0.1	ps (rms)
		QPI & SMI (100.00 MHz, 9.6 Gb/s, 12UI) (Notes 35 and 36)			0.1	ps (rms)

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

31. Applies to all outputs.

32. See http://www.pcisig.com for complete specs

33. Sample size of at least 100k cycles. This figures extrapolates to 108 ps pk-pk @ 1M cycles for a BER of 1–12.

34. Subject to final ratification by PCI SIG.

35. Calculated from Intel-supplied Clock Jitter Tool v 1.6.3

36. For RMS figures, additive jitter is calculated by solving the following equation:  $(Additive jitter)^2 = (total jitter)^2 - (input jitter)^2$ 

#### Table 15. CLOCK PERIODS-DIFFERENTIAL OUTPUTS WITH SPREAD SPECTRUM DISABLED

				Μ	leasurement	Window				
		1 Clock	1 μs	0.1 s	0.1s	0.1s	1 μs	1 Clock		
SSC OFF	Center Freq. MHz	AbsPer	–SSC Short–Term Average Min	– ppm Long-Term Average Min	0 ppm Period Nominal	+ ppm Long– Term Average Max	+SSC Short–Term Average Max	+c2c jitter Abs Per Max	Unit	Notes
DIF	1 00.00	9.94900		9.99900	10 .0000 0	1 0.001 00		10.05100	ns	37, 38, 39
	1 33.33	7.44925		7.49925	7.50000	7.50075		7.55 075	ns	37, 38, 40

37. Guaranteed by design and characterization, not tested in production.

38. All Long Term Accuracy specifications are guaranteed with the assumption that the input clock complies with CK420BQ/CK410B+ accuracy requirements (±100 ppm). The NB3W1900L it self does not contribute to ppm error.

39. Driven by SRC out put of main clock, 100.00 MHz PLL Mode or Bypass mode.

40. Driven by CPU out put of main clock, 133.33 MHz PLL Mode or Bypass mode.

#### Table 16. CLOCK PERIODS-DIFFERENTIAL OUTPUTS WITH SPREAD SPECTRUM ENABLED

				N	leasurement	Window				
		1 Clock	1 μs	0.1s	0.1s	0.1s	1 μs	1 Clock		
SSC ON	Center Freq. MHz	AbsPer	–SSC Short–Term Average Min	-	0 ppm Peri- od Nominal	+ ppm Long– Term Average Max	+SSC Short–Term Average Max	+c2c jitter AbsPer Max	Unit	Notes
DIF	99.75	9.94906	9. 99906	10.02406	10.02506	10.02607	10.05107	10.10107	ns	41, 42, 43
	133.00	7.44930	7. 49930	7.51805	7.51880	7.51955	7.53830	7.58830	ns	41, 42, 44

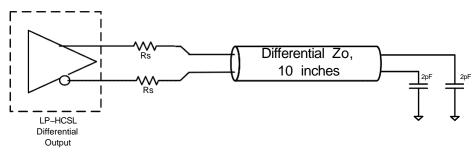
41. Guaranteed by design and characterization, not tested in production.

42. All Long Term Accuracy specifications are guaranteed with the assumption that the input clock complies with CK420BQ/ CK410B+ accuracy requirements (±100 ppm). The NB3W1900L it self does not contribute to ppm error.

43. Driven by SRC out put of main clock, 100.00 MHz PLL Mode or Bypass mode.

44. Driven by CPU out put of main clock, 133.33 MHz PLL Mode or Bypass mode.

### TEST LOADS



#### Figure 3. NB3W1900L Differential Test Loads

#### Table 17. DIFFERENTIAL OUTPUT TERMINATIONS

DIF Zo (Ω)	Rs (Ω)
100	33
85	27

### **GENERAL SMBus SERIAL INTERFACE INFORMATION**

### How to Write

- Controller (host) sends a start bit
- Controller (host) sends the write address
- Clock (device) will **acknowledge**
- Controller (host) sends the beginning byte location = N
- Clock (device) will acknowledge
- Controller (host) sends the byte count = X
- Clock (device) will **acknowledge**
- Controller (host) starts sending Byte N through Byte N+X-1
- Clock (device) will **acknowledg**e each byte **one at a time**
- Controller (host) sends a Stop bit

### Table 18. INDEX BLOCK WRITE OPERATION

C	ontroller (Host	)	Clock (Device)
Т	starT bit		
Slav	e Address		
WR	WRite		
			ACK
Beginn	ing Byte = N		
			ACK
Data By	/te Count = X		
			ACK
Begin	ning Byte N		
		X Byte	ACK
0			
0			0
0			0
			0
Byte	N + X – 1	1	
		1	ACK
Р	stoP bit		

### How to Read

- Controller (host) will send a start bit
- Controller (host) sends the write address
- Clock (device) will acknowledge

- Controller (host) sends the beginning byte location = N
- Clock (device) will acknowledge
- Controller (host) will send a separate start bit
- Controller (host) sends the read address
- Clock (device) will **acknowledge**
- Clock (device) will send the data byte count = X
- Clock (device) sends Byte N + X 1
- Clock (device) sends Byte 0 through Byte X (if X<sub>(H)</sub> was written to Byte 8)
- Controller (host) will need to acknowledge each byte
- Controller (host) will send a not acknowledge bit
- Controller (host) will send a stop bit

### Table 19. INDEX BLOCK READ OPERATION

		1	
	oller (Host)		Clock (Device)
Т	starT bit		
Slav	e Address		
WR	WRite		
			ACK
Beginn	ing Byte = N		
			ACK
RT	Repeat starT	1	
Slav	e Address	1	
RD	ReaD	1	
			ACK
		X Byte	
		, A Byte	Data Byte Count = X
	ACK		
			Beginning Byte N
	ACK		
			0
	0	]	0
	0	]	0
	0		
			Byte N + X – 1
N	Not acknowledge		
Р	stoP bit		

SA_1 and SA_0	SMBus 8-bit Address (Rd/Wrt bit = 0)
00	D8
OM	DA
01	DE
MO	C2
MM	C4
M1	C6
10	CA
1M	CC
11	CE

### Table 20. SMBus ADDRESSING

### Table 21. SMBus Table: PLL MODE, AND FREQUENCY SELECT REGISTER

Byte 0	Pin #	Name	Control Function	Туре	0 1		Default
Bit 7	4	PLL Mode 1	PLL Operating Mode Rd back 1	R		See PLL Operating Mode	
Bit 6	4	PLL Mode 0	PLL Operating Mode Rd back 0	R	Readback Table		Latch
Bit 5	72/71	DIF_18_En	Output Control overrides OE# pin	RW	Low/Low	Enable	1
Bit 4	68/67	DIF_17_En	Output Control overrides OE# pin	RW	Low/Low Enable		1
Bit 3	66/65	DIF_16_En	Output Control overrides OE# pin	RW	Low/Low	Enable	1
Bit 2			Reserved				0
Bit 1			Reserved				0
Bit 0	3	100M_133M#	Frequency Select Readback	R	133 MHz	100 MHz	Latch

### Table 22. SMBus TABLE: OUTPUT CONTROL REGISTER

Byte 1	Pin #	Name	Control Function	Туре	0	1	Default
Bit 7	38/37	DIF_7_En	Output Control overrides OE# pin	RW			1
Bit 6	35/36	DIF_6_En	Output Control overrides OE# pin	RW			1
Bit 5	31/32	DIF_5_En	Output Control overrides OE# pin	RW			1
Bit 4	29/30	DIF_4_En	Output Control overrides OE# pin	RW		Frabla	1
Bit 3	25/26	DIF_3_En	Output Control overrides OE# pin	RW	Low/Low	Enable	1
Bit 2	23/24	DIF_2_En	Output Control overrides OE# pin	RW			1
Bit 1	19/20	DIF_1_En	Output Control overrides OE# pin	RW	]		
Bit 0	17/18	DIF_0_En	Output Control overrides OE# pin	RW			1

### Table 23. SMBus TABLE: OUTPUT CONTROL REGISTER

Byte 2	Pin #	Name	Control Function	Туре	0	1	Default
Bit 7	62/61	DIF_15_En	Output Control overrides OE# pin	RW			1
Bit 6	60/59	DIF_14_En	Output Control overrides OE# pin	RW			1
Bit 5	56/55	DIF_13_En	Output Control overrides OE# pin	RW			1
Bit 4	54/53	DIF_12_En	Output Control overrides OE# pin	RW	1/1		1
Bit 3	50/49	DIF_11_En	Output Control overrides OE# pin	RW	Low/Low	Enable	1
Bit 2	48/47	DIF_10_En	Output Control overrides OE# pin	RW			1
Bit 1	44/43	DIF_9_En	Output Control overrides OE# pin	RW			1
Bit 0	42/41	DIF_8_En	Output Control overrides OE# pin	RW	1		1

### Table 24. SMBus TABLE: RESERVED REGISTER

Byte 3	Pin #	Name	Control Function	Туре	0	1	Default
Bit 7			Reserved				0
Bit 6			Reserved				0
Bit 5			Reserved				0
Bit 4		Reserved				0	
Bit 3			Reserved				0
Bit 2			Reserved				0
Bit 1			Reserved				0
Bit 0			Reserved				0

#### Table 25. SMBus TABLE: RESERVED REGISTER

Byte 4	Pin #	Name	Control Function	Туре	0	1	Default
Bit 7			Reserved				0
Bit 6			Reserved				0
Bit 5			Reserved				0
Bit 4			Reserved				0
Bit 3			Reserved				0
Bit 2			Reserved				0
Bit 1			Reserved				0
Bit 0			Reserved				0

### Table 26. SMBus TABLE: VENDOR & REVISION ID REGISTER

Byte 5	Pin #	Name	Control Function	Туре	0	1	Default
Bit 7	_	RID3		R	-	-	Х
Bit 6	_	RID2	REVISION ID	R	-	-	Х
Bit 5	_	RID1	REVISIONID	R	-	-	Х
Bit 4	_	RID0		R	-	-	Х
Bit 3	_	VID3		R	-	-	1
Bit 2	_	VID2	VENDOR ID	R	-	-	1
Bit 1	_	VID1	VENDOR ID	R	-	-	1
Bit 0	-	VID0		R	-	-	1

### Table 27. SMBus TABLE: DEVICE ID

Byte 6	Pin #	Name	Control Function	Туре	0	1	Default
Bit 7	-	De	Device ID 7 (MSB)				1
Bit 6	-		Device ID 6				1
Bit 5	-	Device ID 5		R			0
Bit 4	-		Device ID 4		Device ID is 130 decimal or		1
Bit 3	-		Device ID 3	R	82	nex.	1
Bit 2	-		Device ID 2	R			0
Bit 1	-	Device ID 1		R	]		1
Bit 0	_		Device ID 0				1

### Table 28. SMBus TABLE: BYTE COUNT REGISTER

Byte 7	Pin #	Name	Control Function	Туре	0	1	Default
Bit 7		Reserved					0
Bit 6			Reserved				
Bit 5		Reserved					0
Bit 4	-	BC4		RW			0
Bit 3	-	BC3		RW	Default value	is 8 hey so 9	1
Bit 2	-	BC2	Writing to this register configures how many bytes will be read back.	RW	<ul> <li>Default value is 8 hex, so 9 bytes (0 to 8) will be read back by default.</li> </ul>		0
Bit 1	-	BC1		RW			0
Bit 0	—	BC0		RW	1		0

### Table 29. SMBus TABLE: RESERVED REGISTER

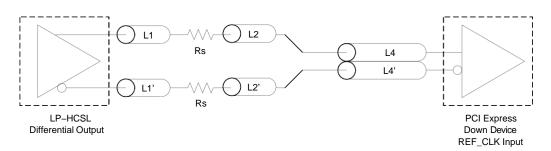
Byte 8	Pin #	Name	Control Function	Туре	0	1	Default
Bit 7			Reserved				0
Bit 6			Reserved				0
Bit 5			Reserved				0
Bit 4		Reserved				0	
Bit 3			Reserved				0
Bit 2			Reserved				0
Bit 1			Reserved				0
Bit 0			Reserved	Reserved			

### Table 30. DIF REFERENCE CLOCK

Common R Recommendations for Differential Routing	Dimension or Value	Unit
L1 length, route as non-coupled 50 $\Omega$ trace (see Figure 4)	0.5 max	inch
L2 length, route as non-coupled 50 $\Omega$ trace (see Figure 4)	0.2 max	inch
L3 length, route as non-coupled 50 $\Omega$ trace (see Figure 4)	0.2 max	inch
Rs (100 $\Omega$ differential traces) (see Figure 4)	33	Ω
Rs (85 $\Omega$ differential traces) (see Figure 4)	27	Ω

Down Device Differential Routing		
L4 length, route as coupled micro strip 100 $\Omega$ differential trace (see Figure 4)	2 min to 16 max	inch
L4 length, route as coupled strip line 100 $\Omega$ differential trace (see Figure 4)	1.8 min to 14.4 max	inch

Differential Routing to PCI Express Connector		
L4 length, route as coupled microstrip 100 $\Omega$ differential trace (see Figure 5)	0.25 to 14 max	inch
L4 length, route as coupled stripline 100 $\Omega$ differential trace (see Figure 5)	0.225 min to 12.6 max	inch





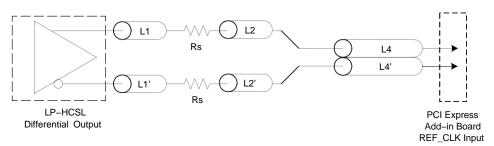


Figure 5. PCI Express Connector Routing

Table 31. CABLE CONNECTED AC COUPLED	APPLICATION (Figure 6)

Component	Value	Note
R5a, R5b	8.2k 5%	
R6a, R6b	1k 5%	
Cc	0.1 μF	
Vcm	0.350 V	

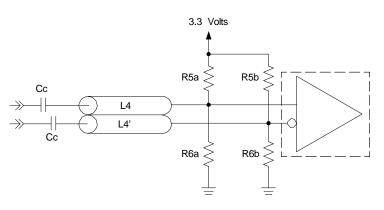


Figure 6.

### POWER FILTERING EXAMPLE

### Ferrite Bead Power Filtering

Recommended ferrite bead filtering equivalent to the following: 600 Q impedance at 100.00 MHz,  $\leq 0.1$  Q DCR max.,  $\geq 400$  mA current rating.

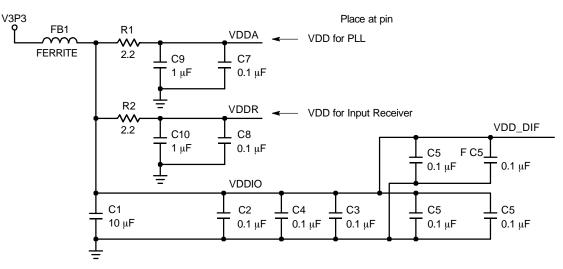


Figure 7. Schematic Example of the NB3W1900L Power Filtering

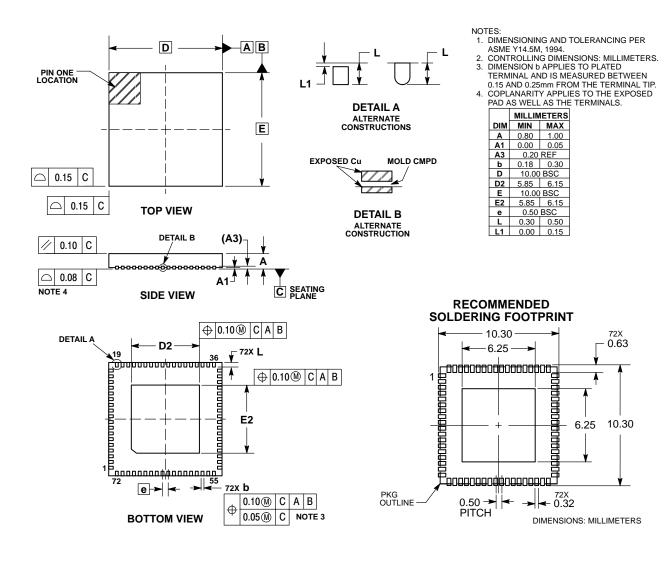
### Table 32. ORDERING INFORMATION

Device	Package	Shipping <sup>†</sup>
NB3W1900LMNG	QFN-72 (Pb-Free)	168 Units / Tray
NB3W1900LMNTXG	QFN-72 (Pb-Free)	1,000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

#### PACKAGE DIMENSIONS

QFN72 10x10, 0.5P CASE 485DK ISSUE O



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